Product data sheet

1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in an MLPAK33 (SOT8002) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Low threshold voltage
- Trench MOSFET technology
- MLPAK33 package (3.3 x 3.3 mm footprint)

3. Applications

- · High-side load switch
- Battery management
- DC-to-DC conversion
- Switching circuits

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	-20	V
V_{GS}	gate-source voltage			-12	-	12	V
I _D	drain current	$V_{GS} = -4.5 \text{ V}; T_{amb} = 25 \text{ °C}; t \le 5 \text{ s}$	[1]	-	-	-12.1	Α
Static characte	Static characteristics						
R _{DSon}	drain-source on-state	$V_{GS} = -4.5 \text{ V}; I_D = -7.7 \text{ A}; T_j = 25 ^{\circ}\text{C}$		-	16	20	mΩ
	resistance	V_{GS} = -2.5 V; I_D = -5.8 A; T_j = 25 °C		-	26.4	35.2	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².



5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	1 2 3 4	
2	S	source		
3	S	source		D
4	G	gate		
5	D	drain		
6	D	drain	Lanah	\$ 017aaa257
7	D	drain	8 7 6 5	- // 34425/
8	D	drain	MLPAK33 (SOT8002-1)	

6. Ordering information

Table 3. Ordering information

Type number	Package						
	Name	Description	Version				
PXP020-20QX		plastic thermal enhanced surface mounted package; mini leads; 8 terminals; pitch 0.65 mm; 3.3 x 3.3 x 0.8 mm body	SOT8002-1				

7. Marking

Table 4. Marking codes

Type number	Marking code
PXP020-20QX	8AD

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{DS}	drain-source voltage	T _j = 25 °C		-	-20	V
V _{GS}	gate-source voltage			-12	12	V
I _D	drain current	V _{GS} = -4.5 V; T _{amb} = 25 °C; t ≤ 5 s	[1]	-	-12.1	Α
		V _{GS} = -4.5 V; T _{amb} = 25 °C	[1]	-	-8	Α
		V _{GS} = -4.5 V; T _{amb} = 100 °C	[1]	-	-4.8	Α
		V _{GS} = -4.5 V; T _{sp} = 25 °C		-	-23.5	Α
I _{DM}	peak drain current	T _{amb} = 25 °C; single pulse; t _p ≤ 10 μs		-	-42.4	Α
P _{tot}	total power dissipation	T _{amb} = 25 °C; t ≤ 5 s	[1]	-	4.2	W
		T _{amb} = 25 °C	[1]	-	1.7	W
		T _{sp} = 25 °C		-	15	W
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-drai	n diode		'	'	'	,
I _S	source current	T _{amb} = 25 °C	[1]	-	-1.7	Α

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

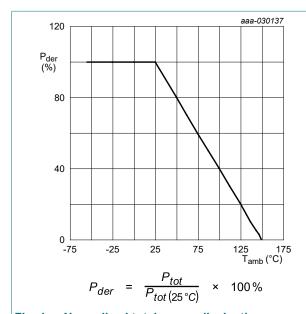


Fig. 1. Normalized total power dissipation as a function of ambient temperature

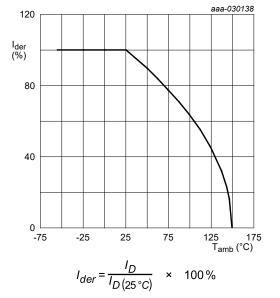


Fig. 2. Normalized continuous drain current as a function of ambient temperature

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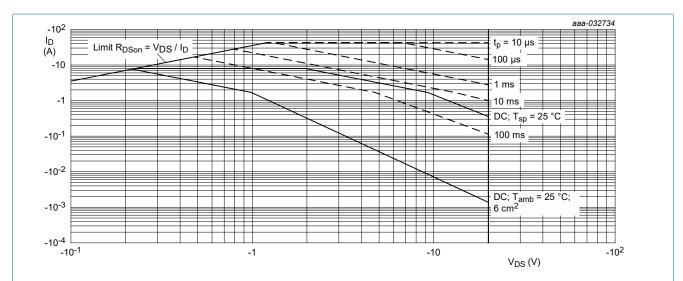


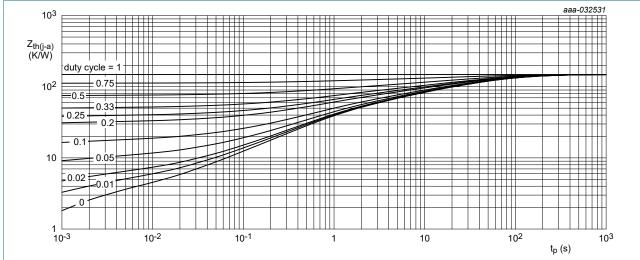
Fig. 3. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage

9. Thermal characteristics

Table 6. Thermal characteristics

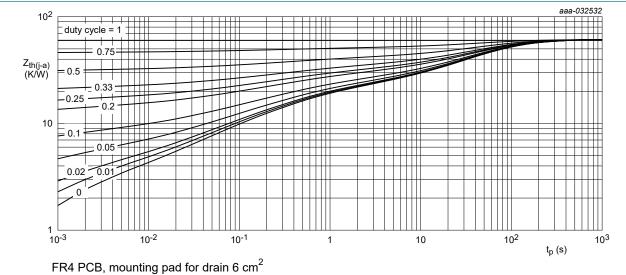
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from	in free air	[1]	-	150	190	K/W
junction to aml	junction to ambient		[2]	-	60	75	K/W
		in free air; t ≤ 5 s	[2]	-	25	30	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	4	8	K/W

- Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².



FR4 PCB, standard footprint

Transient thermal impedance from junction to ambient as a function of pulse duration; typical values Fig. 4.



Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _{(BR)DSS}	drain-source breakdown voltage	I_D = -250 μ A; V_{GS} = 0 V; T_j = 25 °C	-20	-	-	V
V_{GSth}	gate-source threshold voltage	$I_D = -250 \ \mu A; \ V_{DS} = V_{GS}; \ T_j = 25 \ ^{\circ}C$	-0.7	-0.9	-1.25	V
I _{DSS}	drain leakage current	V _{DS} = -20 V; V _{GS} = 0 V; T _j = 25 °C	-	-	-1	μA
I _{GSS}	gate leakage current	V _{GS} = -12 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-100	nA
		V _{GS} = 12 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
R _{DSon}	drain-source on-state	$V_{GS} = -4.5 \text{ V}; I_D = -7.7 \text{ A}; T_j = 25 \text{ °C}$	-	16	20	mΩ
	resistance	V_{GS} = -4.5 V; I_D = -7.7 A; T_j = 150 °C	-	22.7	28.4	mΩ
		V_{GS} = -2.5 V; I_D = -5.8 A; T_j = 25 °C	-	26.4	35.2	mΩ
9fs	forward transconductance	$V_{DS} = -10 \text{ V}; I_D = -7.7 \text{ A}; T_j = 25 \text{ °C}$	-	21.4	-	S
R_G	gate resistance	f = 1 MHz	-	6.4	-	Ω
Dynamic ch	aracteristics		1		1	
Q _{G(tot)}	total gate charge	$V_{DS} = -10 \text{ V}; I_D = -7.7 \text{ A}; V_{GS} = -4.5 \text{ V};$	-	19.4	29.1	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	3.4	-	nC
Q _{GS(th)}	pre-threshold gate- source charge		-	1.6	-	nC
Q _{GS(th-pl)}	post-threshold gate- source charge		-	1.8	-	nC
Q_{GD}	gate-drain charge		-	6.2	-	nC
V_{GSpl}	gate-source plateau voltage	$V_{DS} = -10 \text{ V}; I_D = -7.7 \text{ A}; T_j = 25 \text{ °C}$	-	-1.8	-	V
C _{iss}	input capacitance	V _{DS} = -10 V; f = 1 MHz; V _{GS} = 0 V;	-	1900	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	275	-	pF
C _{rss}	reverse transfer capacitance		-	250	-	pF
$t_{d(on)}$	turn-on delay time	$V_{DS} = -10 \text{ V}; I_D = -5.8 \text{ A}; V_{GS} = -4.5 \text{ V};$	-	6	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 ^{\circ}C$	-	23	-	ns
t _{d(off)}	turn-off delay time	1	-	46	-	ns
t _f	fall time	1	-	31	-	ns
Source-drai	in diode		1		1	
V _{SD}	source-drain voltage	I _S = -1.7 A; V _{GS} = 0 V; T _j = 25 °C	-	-0.7	-1.2	V
t _{rr}	reverse recovery time	$I_S = -1.7 \text{ A}$; $dI_S/dt = 100 \text{ A/µs}$;	-	26	-	ns
Q _r	recovered charge	$V_{GS} = -4.5 \text{ V}; V_{DS} = -10 \text{ V}; T_j = 25 \text{ °C}$	-	10	-	nC
t _a	reverse recovery rise time	1	-	6	-	ns
t _b	reverse recovery fall time	-	-	20	-	ns

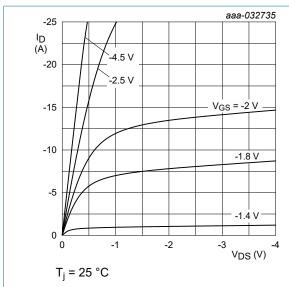


Fig. 6. Output characteristics: drain current as a function of drain-source voltage; typical values

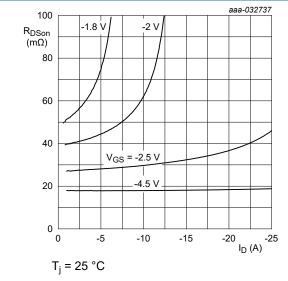


Fig. 8. Drain-source on-state resistance as a function of drain current; typical values

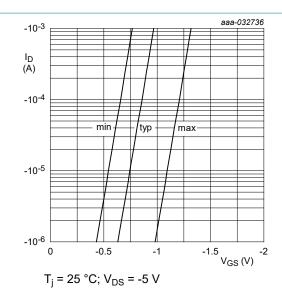


Fig. 7. Sub-threshold drain current as a function of

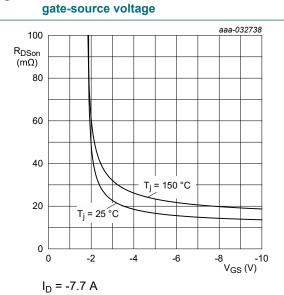


Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

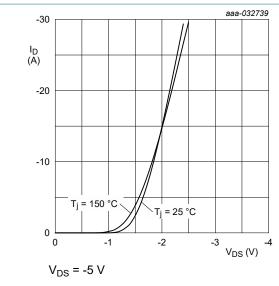


Fig. 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values

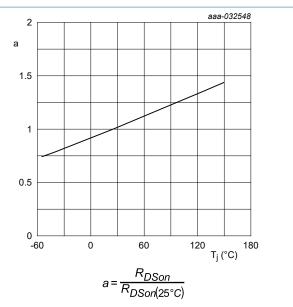


Fig. 11. Normalized drain-source on-state resistance as a function of junction temperature; typical values

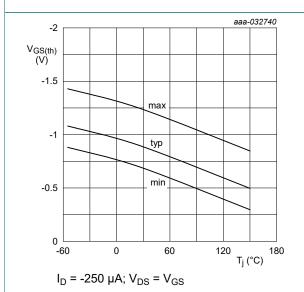
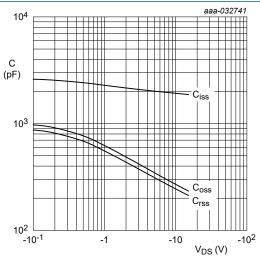


Fig. 12. Gate-source threshold voltage as a function of junction temperature



 $f = 1 MHz; V_{GS} = 0 V$

Fig. 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

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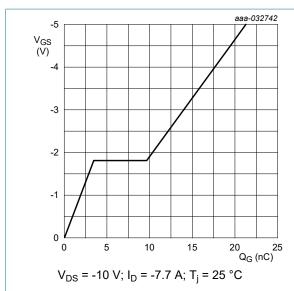


Fig. 14. Gate-source voltage as a function of gate charge; typical values

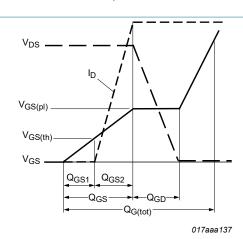


Fig. 15. Gate charge waveform definitions

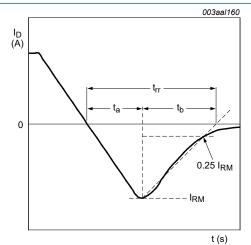


Fig. 16. Reverse recovery timing definition

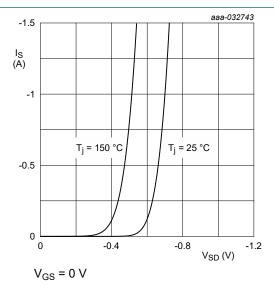
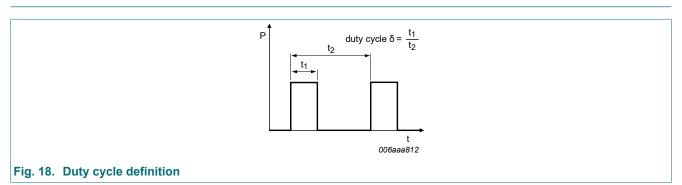


Fig. 17. Source current as a function of source-drain voltage; typical values

11. Test information



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12. Package outline

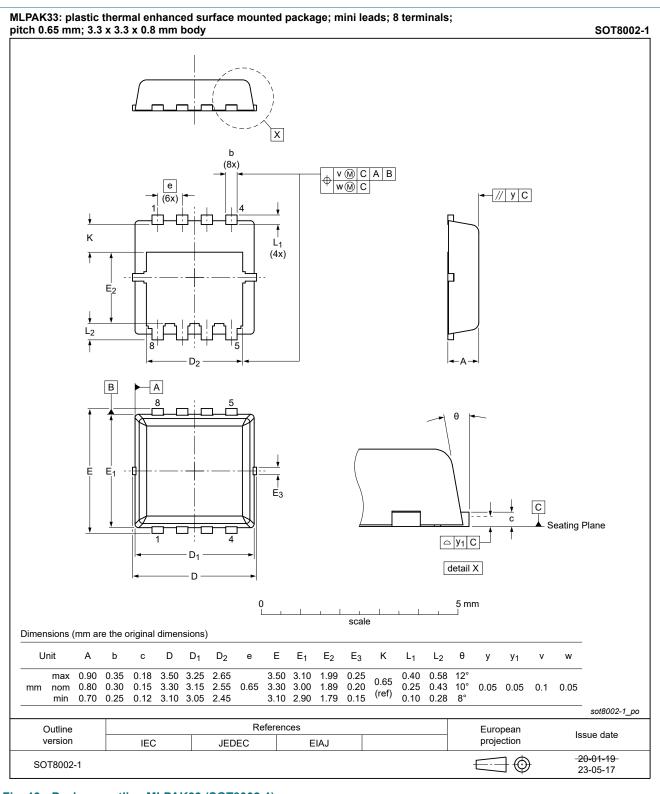
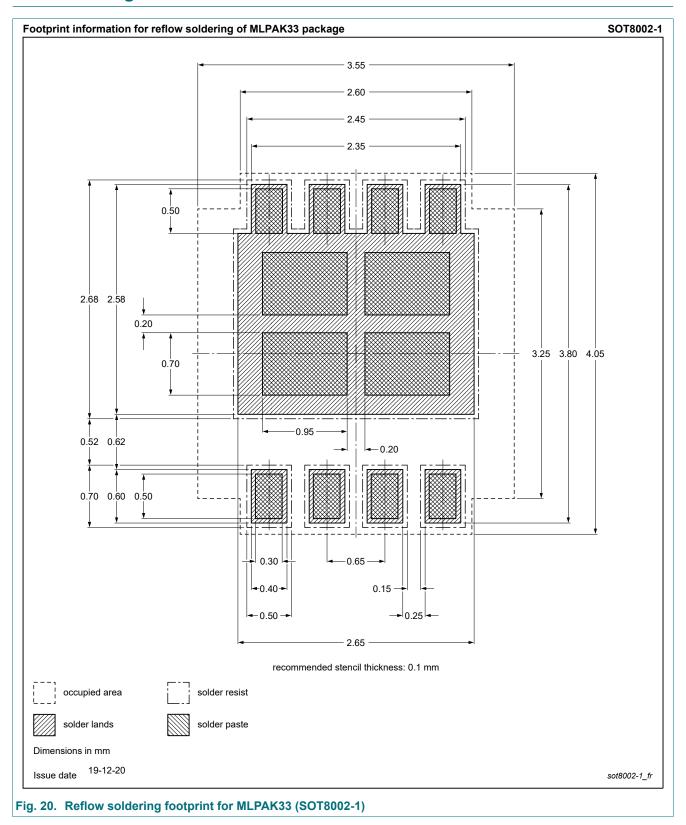


Fig. 19. Package outline MLPAK33 (SOT8002-1)

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13. Soldering



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14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PXP020-20QX v.3	20230731	Product data sheet	-	PXP020-20QX v.2			
Modifications:	Chapter "Package or	Chapter "Package outline": drawing update					
PXP020-20QX v.2	20211026	Product data sheet	-	PXP020-20QX v.1			
PXP020-20QX v.1	20210414	Product data sheet	-	-			

Product data sheet

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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